# **74AUP2G80**

Low-power dual D-type flip-flop; positive-edge trigger

Rev. 9 — 18 August 2017 Product data sheet

### 1 General description

The 74AUP2G80 provides the dual positive-edge triggered D-type flip-flop. Information on the data input is transferred to the  $\overline{\mathbb{Q}}$  output on the LOW-to-HIGH transition of the clock pulse. The input pin D must be stable one setup time prior to the LOW-to-HIGH clock transition for predictable operation.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

### 2 Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- · Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- · ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5 000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1 000 V
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



# 3 Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G80DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G80GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm	SOT833-1
74AUP2G80GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm	SOT1089
74AUP2G80GD	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 3 x 2 x 0.5 mm	SOT996-2
74AUP2G80GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm	SOT902-2
74AUP2G80GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm	SOT1116
74AUP2G80GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm	SOT1203

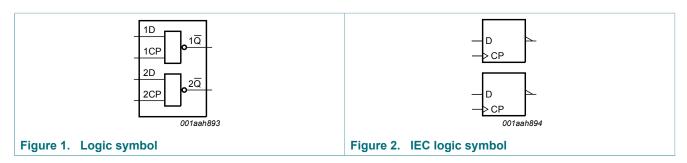
# 4 Marking

Table 2. Marking codes

Type number	Marking code <sup>[1]</sup>
74AUP2G80DC	p80
74AUP2G80GT	p80
74AUP2G80GF	рТ
74AUP2G80GD	p80
74AUP2G80GM	p80
74AUP2G80GN	рТ
74AUP2G80GS	рТ

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5 Functional diagram

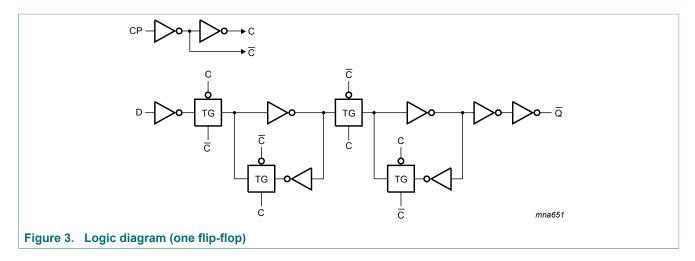


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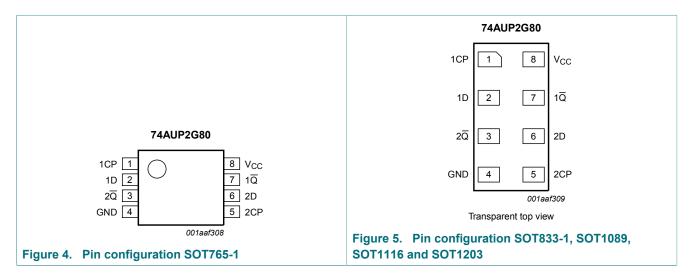
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Low-power dual D-type flip-flop; positive-edge trigger

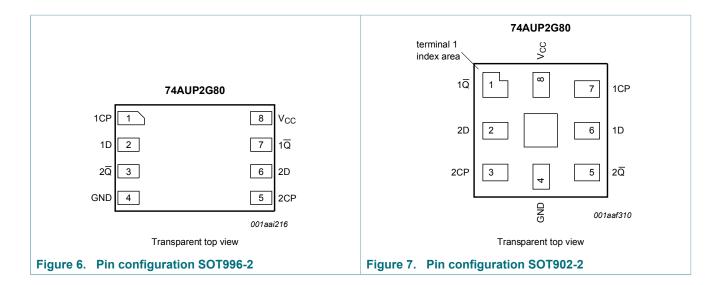


# 6 Pinning information

### 6.1 Pinning



### Low-power dual D-type flip-flop; positive-edge trigger



### 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Pin				
	SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203	SOT902-2				
1CP, 2CP	1, 5	7, 3	clock input			
1D, 2D	2, 6	6, 2	data input			
GND	4	4	ground (0 V)			
1 <u>Q</u> , 2 <u>Q</u>	7, 3	1, 5	data output			
$V_{CC}$	8	8	supply voltage			

# 7 Functional description

Table 4. Function table [1]

Input		Output
nCP	nD	nQ
<b>↑</b>	L	Н
$\uparrow$	н	L
L	X	q

- [1] H = HIGH voltage level;
  - L = LOW voltage level;
  - $\uparrow$  = LOW-to-HIGH CP transition;
  - X = don't care;
  - $\overline{q}$  = lower case letter indicates the state of referenced input, one setup time prior to the LOW-to-HIGH CP transition.

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# 8 Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Parameter	Conditions		Min	Max	Unit
supply voltage			-0.5	+4.6	V
input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
input voltage		[1]	-0.5	+4.6	V
output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
supply current			-	+50	mA
ground current			-50	-	mA
storage temperature			-65	+150	°C
total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	250	mW
	supply voltage input clamping current input voltage output clamping current output voltage output current supply current ground current storage temperature	$\begin{array}{c} \text{supply voltage} \\ \text{input clamping current} & V_{\text{I}} < 0 \text{ V} \\ \text{input voltage} \\ \text{output clamping current} & V_{\text{O}} < 0 \text{ V} \\ \text{output voltage} & \text{Active mode and Power-down mode} \\ \text{output current} & V_{\text{O}} = 0 \text{ V to V}_{\text{CC}} \\ \text{supply current} \\ \text{ground current} \\ \text{storage temperature} \end{array}$	supply voltage  input clamping current  input voltage  output clamping current $V_0 < 0 \text{ V}$ output voltage  Active mode and Power-down mode  [1]  output current $V_0 = 0 \text{ V}$ to $V_{CC}$ supply current  ground current  storage temperature	supply voltage $-0.5$ input clamping current $V_I < 0 \text{ V}$ $-50$ input voltage $[1]$ $-0.5$ output clamping current $V_O < 0 \text{ V}$ $-50$ output voltageActive mode and Power-down mode $[1]$ $-0.5$ output current $V_O = 0 \text{ V to V}_{CC}$ $-$ supply current $ -$ ground current $ -$ storage temperature $ -$	supply voltage-0.5+4.6input clamping current $V_1 < 0 \text{ V}$ -50-input voltage $\begin{bmatrix} 11 \end{bmatrix}$ -0.5+4.6output clamping current $V_O < 0 \text{ V}$ -50-output voltageActive mode and Power-down mode $\begin{bmatrix} 11 \end{bmatrix}$ -0.5+4.6output current $V_O = 0 \text{ V to V}_{CC}$ - $\pm 20$ supply current-+50ground current-50-storage temperature-65+150

 <sup>[1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 [2] For VSSOP8 packages: above 110 °C the value of P<sub>tot</sub> derates linearly with 8.0 mW/K.

### 9 Recommended operating conditions

**Table 6. Operating conditions** 

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	-	200	ns/V

<sup>[2]</sup> For VSSOP8 packages: above 110 °C the value of P<sub>tot</sub> derates linearly with 8.0 mW/K.
For XSON8 and XQFN8 packages: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

### 10 Static characteristics

**Table 7. Static characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 25	s°C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 x V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 x V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 x V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 x V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 x V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	-	V	
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{\rm O}$ = -2.3 mA; $V_{\rm CC}$ = 2.3 V	2.05	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC}$ = 2.3 V	1.9	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.72	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.30 x V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	2.0 0.30 x V <sub>CC</sub> N - 0.35 x V <sub>CC</sub> N - 0.7 N - 0.9	V	
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.30 x V <sub>CC</sub> 0.35 x V <sub>CC</sub> 0.7 0.9 0.9 0.1 0.30 x V <sub>CC</sub> 0.31 0.31 0.31 0.31 0.44 0.31 0.31 0.31 0.31 0.31 0.31 0.31 0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
lį	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_{I}$ = GND or $V_{CC}$	-	0.6	-	pF
Co	output capacitance	V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V	-	1.3	-	pF
T <sub>amb</sub> = -4	0 °C to +85 °C				1	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.70 x V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.65 x V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.30 x V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.35 x V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.70 x V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		$I_{\rm O}$ = -4.0 mA; $V_{\rm CC}$ = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.30 x V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.5	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μA
Δl <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μΑ
$T_{amb} = -40$	0 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 0.8 V	0.75 x V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 x V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 0.8 V	-	-	0.25 x V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 x V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.60 x V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 x V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ

## Low-power dual D-type flip-flop; positive-edge trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_1 \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μΑ
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μΑ

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

# 11 Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 10.

Symbol	Parameter	Conditions		<sub>nb</sub> = 25	°C	Ta	<sub>mb</sub> = -40	°C to +12	5 °C	Unit
			Min	Typ <sup>[1]</sup>	Max		Max (85 °C)	Min (125 °C)	Max (125 °C)	
C <sub>L</sub> = 5 pF										
t <sub>pd</sub>	propagation	nCP to nQ; see Figure 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	20.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.9	6.0	12.9	2.6	14.3	2.6	15.7	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	1.9	4.2	7.6	2.0	8.9	2.0	9.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.7	3.4	5.9	1.6	7.0	1.6	7.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.6	4.3	1.2	5.6	1.2	6.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.2	2.2	3.6	1.0	4.4	1.0	4.8	ns
f <sub>max</sub>	maximum	nCP; see Figure 9								
	frequency	V <sub>CC</sub> = 0.8 V	-	53	-	-	-	-	-	MHz
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	203	-	170	-	170	-	MHz
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	347	-	310	-	300	-	MHz
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	435	-	400	-	390	-	MHz
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	550	-	490	-	480	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	619	-	550	-	510	-	MHz

Symbol	Parameter	Conditions	Tan	<sub>nb</sub> = 25	°C	Ta	<sub>mb</sub> = -40	°C to +12	5 °C	Unit
			Min	Typ <sup>[1]</sup>	Max		Max	Min	Max	
						(85 °C)	(85 °C)	(125 °C)	(125 °C)	
C <sub>L</sub> = 10 p		rov		Tr.	I	ı	ı	ı	ı	
t <sub>pd</sub>		nCP to $n\overline{Q}$ ; see Figure 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	24.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.3	6.9	14.9	3.0	16.5	3.0	18.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.6	4.8	8.8	2.3	10.3	2.3	11.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	3.9	6.8	2.0	8.1	2.0	8.9	ns
		$V_{CC}$ = 2.3 V to 2.7 V	1.9	3.1	5.1	1.7	6.3	1.7	6.9	ns
		$V_{CC}$ = 3.0 V to 3.6 V	1.8	2.7	4.4	1.4	4.9	1.4	5.4	ns
f <sub>max</sub>	maximum	nCP; see Figure 9								
	frequency	V <sub>CC</sub> = 0.8 V	-	52	-	-	-	-	-	MHz
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	192	-	150	-	150	-	MHz
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	324	-	280	-	230	-	MHz
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	421	-	310	-	250	-	MHz
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	486	-	370	-	360	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	550	-	410	-	360	-	MHz
$C_L = 15 p$	F									
t <sub>pd</sub>	propagation	nCP to nQ; see Figure 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	28.2	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.0	7.6	16.7	3.4	18.6	3.4	20.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.3	9.8	2.6	11.5	2.6	12.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	4.4	7.6	2.3	9.1	2.3	10.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.2	3.5	5.7	2.0	6.9	2.0	7.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.9	3.1	5.0	1.8	5.5	1.8	6.1	ns
f <sub>max</sub>	maximum	nCP; see Figure 9								
	frequency	V <sub>CC</sub> = 0.8 V	-	50	-	-	-	-	-	MHz
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	181	-	120	-	120	-	MHz
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	301	-	190	-	160	-	MHz
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	407	-	240	-	190	-	MHz
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	422	-	300	-	270	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	481	-	320	-	300	-	MHz

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +125 °C				Unit	
			Min	Typ <sup>[1]</sup>	Max		Max (85 °C)	Min (125 °C)	Max (125 °C)	
C <sub>L</sub> = 30 p	F			I.	I .		ı	ı	ı	
t <sub>pd</sub>	propagation	nCP to nQ; see Figure 8 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	38.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.9	9.8	20.7	4.4	24.7	4.4	27.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.8	12.7	3.5	15.0	3.5	16.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.5	5.6	9.9	2.2	11.9	2.2	13.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.1	4.5	7.5	2.8	9.3	2.8	10.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.9	4.1	6.4	2.7	7.5	2.7	8.3	ns
f <sub>max</sub>	maximum	nCP; see Figure 9								
	frequency	V <sub>CC</sub> = 0.8 V	-	28	-	-	-	-	-	MHz
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	128	-	70	-	70	-	MHz
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	206	-	120	-	110	-	MHz
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	262	-	150	-	120	-	MHz
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	269	-	190	-	170	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	309	-	200	-	190	-	MHz
C <sub>L</sub> = 5 pF	, 10 pF, 15 pF	and 30 pF								
t <sub>su(H)</sub>	set-up time HIGH	nD to nCP; see Figure 9								
		V <sub>CC</sub> = 0.8 V	-	2.5	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	0.5	-	2.3	-	2.3	-	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	0.3	-	1.2	-	1.2	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	0.3	-	0.8	-	0.8	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	0.2	-	0.6	-	0.6	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	0.2	-	0.4	-	0.4	-	ns
t <sub>su(L)</sub>	set-up time	nD to nCP; see Figure 9								
	LOW	V <sub>CC</sub> = 0.8 V	-	1.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	0.3	-	1.9	-	1.9	-	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	0.2	-	1.3	-	1.3	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	0.2	-	1.1	-	1.1	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	0.3	-	0.8	-	0.8	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	0.3	-	0.7	-	0.7	-	ns

### Low-power dual D-type flip-flop; positive-edge trigger

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +125 °C				Unit	
			Min	Typ <sup>[1]</sup>	Max	Min (85 °C)	Max (85 °C)	Min (125 °C)	Max (125 °C)	
t <sub>h</sub>	hold time	nD to nCP; see Figure 9								
		V <sub>CC</sub> = 0.8 V	-	-2.1	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	-0.4	-	0.1	-	0.1	-	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	-0.3	-	0	-	0	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	-0.2	-	0	-	0	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-0.2	-	0	-	0	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-0.3	-	0	-	0	-	ns
t <sub>W</sub>	pulse width	nCP HIGH or LOW; see <u>Figure 9</u>								
		V <sub>CC</sub> = 0.8 V	-	5.2	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	1.0	-	3.0	-	3.0	-	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	8.0	-	2.0	-	2.0	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	0.6	-	2.0	-	2.0	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	0.5	-	2.0	-	2.0	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	0.5	-	2.0	-	2.0	-	ns
$C_{PD}$	power dissipation	$f = 1 \text{ MHz};$ $V_I = GND \text{ to } V_{CC}$ [3]								
	capacitance	V <sub>CC</sub> = 0.8 V	-	1.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	1.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	1.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	2.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	2.4	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	2.9	-	-	-	-	-	pF

All typical values are measured at nominal V<sub>CC</sub>.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

 $f_o$  = output frequency in MHz;

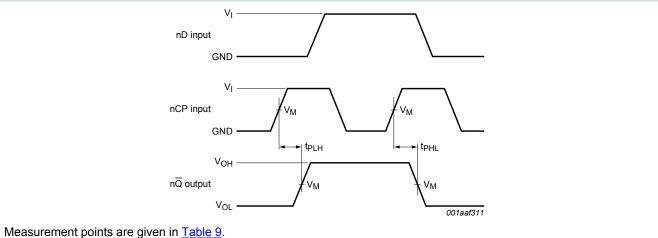
C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;  $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

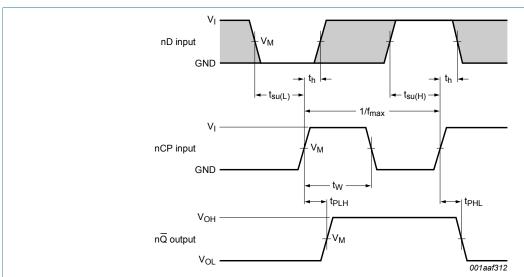
the same as  $t_{PLH}$  and  $t_{PHL}$   $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

#### 11.1 Waveforms and test circuit



Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Figure 8. The clock input (nCP) to output  $(n\overline{Q})$  propagation delays



Measurement points are given in Table 9.

Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Figure 9. The clock input (nCP) to output  $(n\overline{Q})$  propagation delays, clock pulse width, nD to nCP setup and hold times and the nCP maximum frequency

Table 9. Measurement points

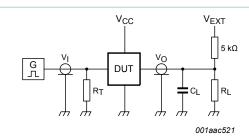
Supply voltage	Output	Input				
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	$t_r = t_f$		
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns		

74AUP2G80

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### Low-power dual D-type flip-flop; positive-edge trigger



Test data is given in Table 10.

Definitions for test circuit:

 $R_L$  = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

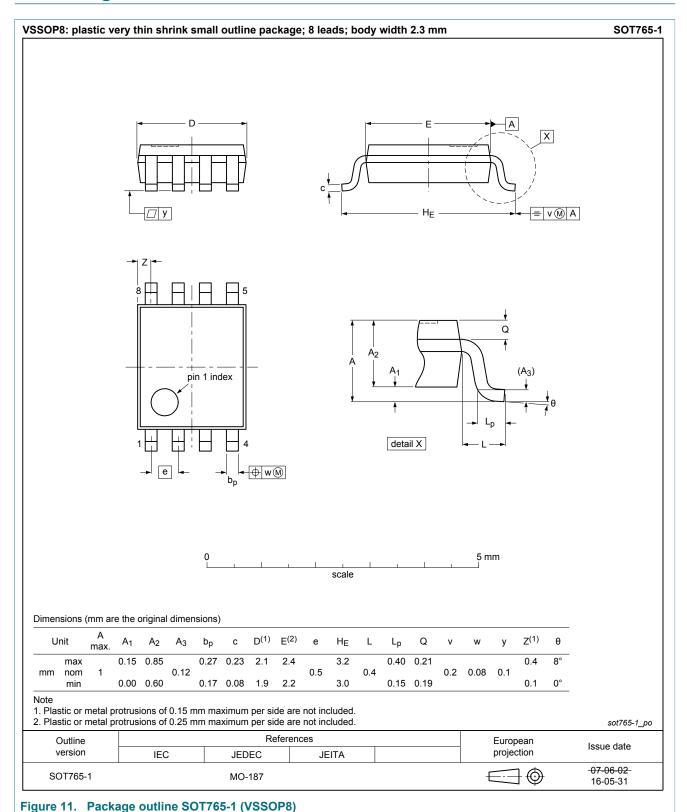
Figure 10. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	C <sub>L</sub>	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 x V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$  For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

# 12 Package outline



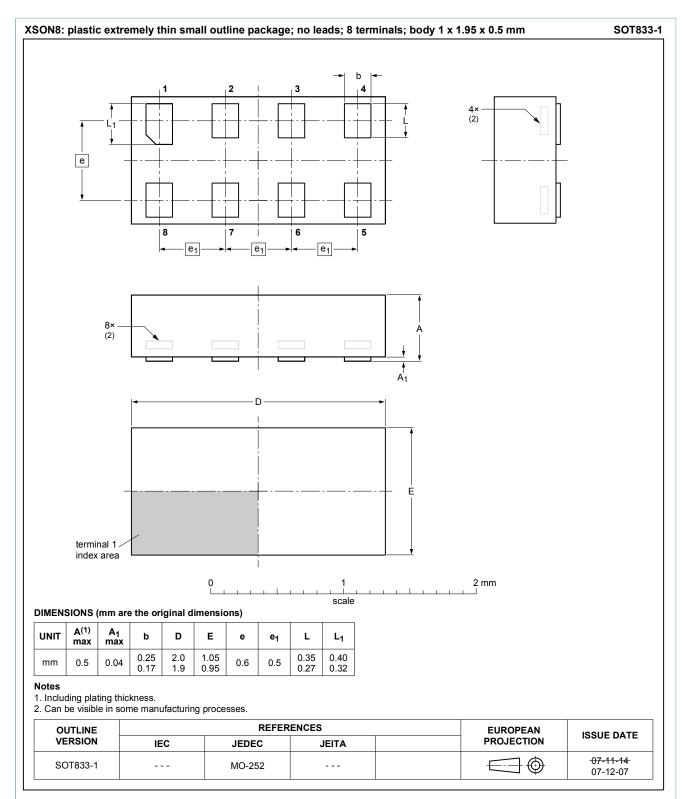
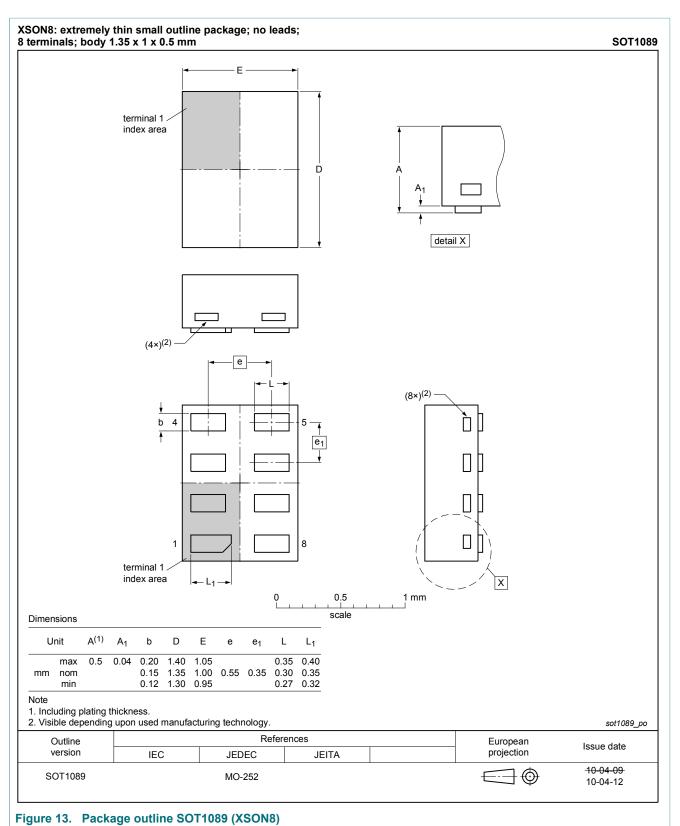
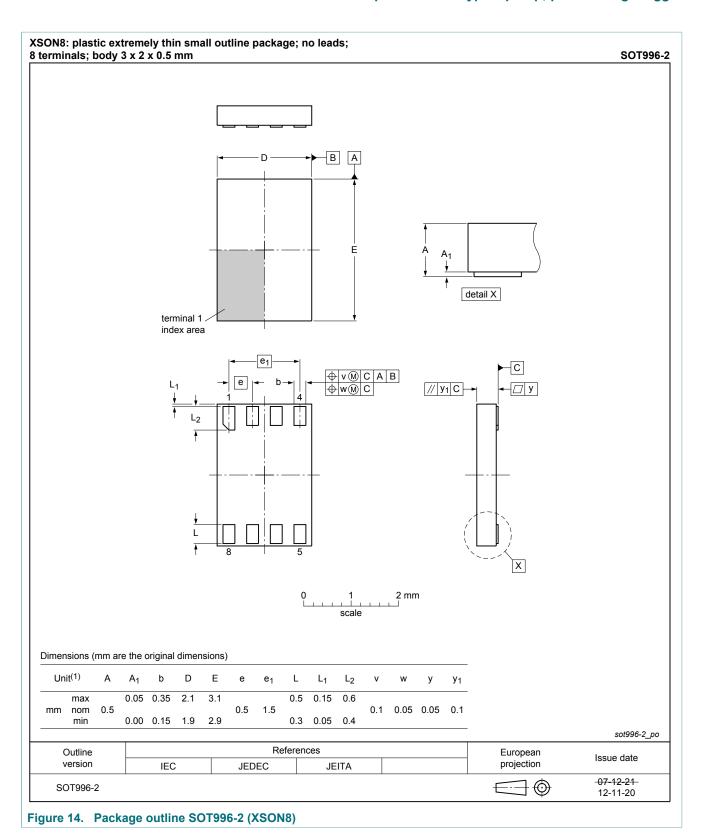


Figure 12. Package outline SOT833-1 (XSON8)





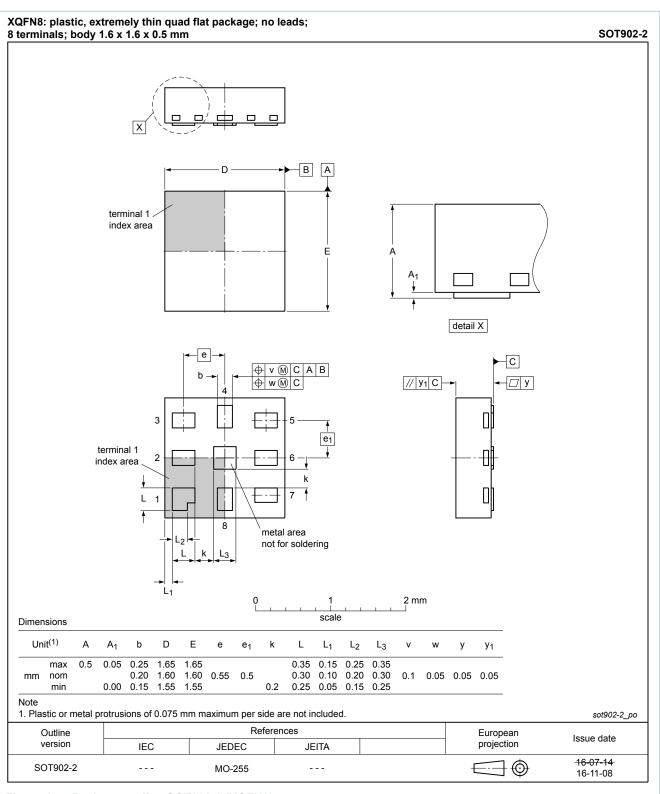


Figure 15. Package outline SOT902-2 (XQFN8)

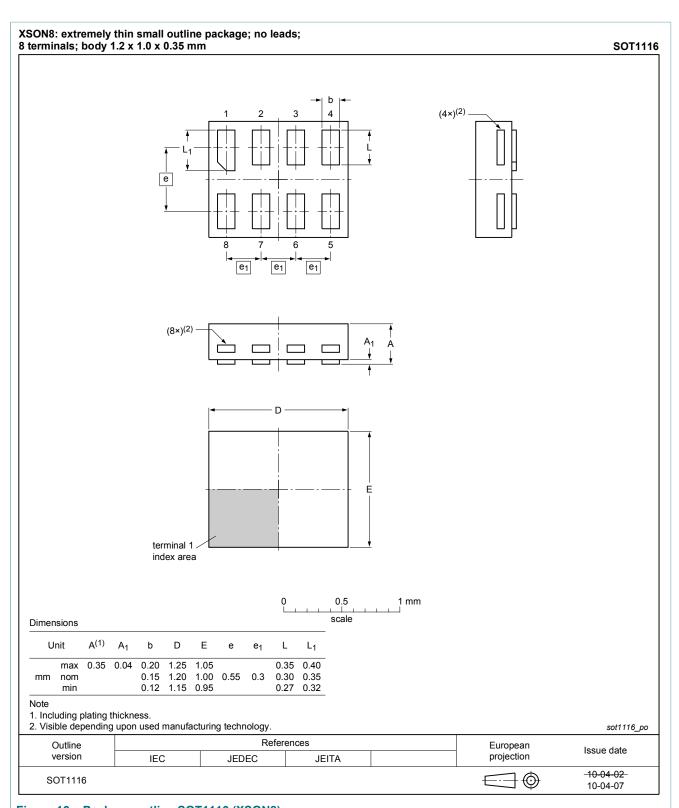


Figure 16. Package outline SOT1116 (XSON8)

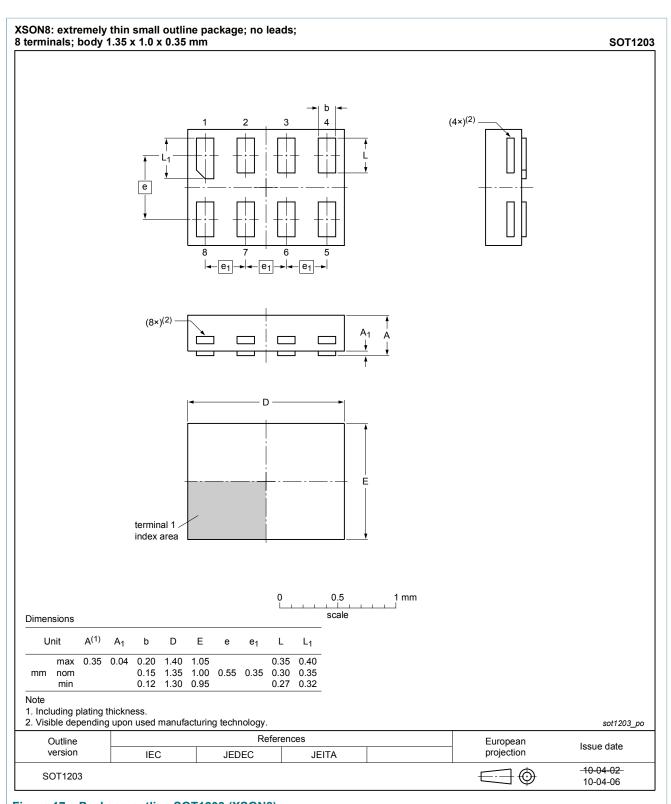


Figure 17. Package outline SOT1203 (XSON8)

### 13 Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

# 14 Revision history

#### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP2G80 v.9	20170818	Product data sheet	-	74AUP2G80 v.8			
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>						
74AUP2G80 v.8	20130121	Product data sheet	-	74AUP2G80 v.7			
Modifications:	For type numbe	r 74AUP2G80GD XSON8U ha	as changed to XSON8.	,			
74AUP2G80 v.7	20120614	Product data sheet	-	74AUP2G80 v.6			
74AUP2G80 v.6	20111207	Product data sheet	-	74AUP2G80 v.5			
74AUP2G80 v.5	20101005	Product data sheet	-	74AUP2G80 v.4			
74AUP2G80 v.4	20080602	Product data sheet	-	74AUP2G80 v.3			
74AUP2G80 v.3	20080328	Product data sheet	-	74AUP2G80 v.2			
74AUP2G80 v.2	20070801	Product data sheet	-	74AUP2G80 v.1			
74AUP2G80 v.1	20060825	Product data sheet	-	-			

### 15 Legal information

#### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions". [2] [3]
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### Low-power dual D-type flip-flop; positive-edge trigger

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